### DATA SHEET



### NPN SILICON GERMANIUM RF TRANSISTOR

# **NESG220033**

# NPN SiGE RF TRANSISTOR FOR UHF-BAND, LOW NOISE, LOW DISTORTION AMPLIFICATION 3-PIN MINIMOLD (33 PKG)

#### **FEATURES**

- The device is an ideal choice for low noise, low distortion amplification.
  - NF = 0.75 dB TYP. @ VcE = 5 V, Ic = 10 mA, f = 1 GHz
- Po (1 dB) = 21.5 dBm TYP. @  $V_{CE} = 5 \text{ V}$ , Ic (set) = 40 mA, f = 1 GHz
- OIP3 = 35 dBm TYP. @ VcE = 5 V, Ic (set) = 40 mA, f = 1 GHz
- Maximum stable power gain: MSG =14.0 dB TYP. @ VcE = 5 V, Ic = 40 mA, f = 1 GHz
- SiGe HBT technology (UHS2): f<sub>T</sub> = 12.5 GHz
- This product is improvement of ESD of NESG2xxx series.
- 3-pin minimold (33 PKG)

#### ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
NESG220033	NESG220033-A	3-pin minimold (33 PKG) (Pb-Free)	50 pcs (Non reel)	8 mm wide embossed taping     Pin 3 (Collector) face the perforation side
NESG220033-T1B	NESG220033-T1B-A		3 kpcs/reel	of the tape

**Remark** To order evaluation samples, please contact your nearby sales office. Unit sample quantity is 50 pcs.

#### ABSOLUTE MAXIMUM RATINGS ( $T_A = +25$ °C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vcво	5.5	V
Collector to Emitter Voltage	Vces	13	V
Collector to Emitter Voltage	Vceo	5.5	V
Base Current Note 1	Ів	36	mA
Collector Current	lc	200	mA
Total Power Dissipation	Ptot Note 2	480	mW
Junction Temperature	Tj	150	°C
Storage Temperature	T <sub>stg</sub>	-65 to +150	°C

Notes 1. Depend on the ESD protect device.

**2.** Mounted on 3.8 cm  $\times$  9.0 cm  $\times$  0.8 mm (t) glass epoxy PWB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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### THERMAL RESISTANCE (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Termal Resistance from Junction to Ambient Note	Rth <sub>j-a</sub>	260	°C/W

Note Mounted on 3.8 cm  $\times$  9.0 cm  $\times$  0.8 mm (t) glass epoxy PWB

### RECOMMENDED OPERATING RANGE ( $T_A = +25$ °C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Collector Current	Ic	-	40	-	mA

### **ELECTRICAL CHARACTERISTICS (TA = +25°C)**

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	Ісво	VcB = 5 V, IE = 0 mA	_	_	100	nA
Emitter Cut-off Current	ІЕВО	V <sub>EB</sub> = 0.4 V, I <sub>C</sub> = 0 mA	_	_	100	nA
DC Current Gain	hfe Note 1	VcE = 5 V, Ic = 10 mA	140	180	260	_
RF Characteristics						
Gain Bandwidth Product	f⊤	VcE = 5 V, Ic = 40 mA, f = 1 GHz	_	12.5	_	GHz
Insertion Power Gain	S <sub>21e</sub>   <sup>2</sup>	VcE = 5 V, Ic = 40 mA, f = 1 GHz	11.0	13.0	_	dB
Noise Figure (1)	NF1	$V_{\text{CE}} = 5 \text{ V, lc} = 10 \text{ mA, f} = 1 \text{ GHz,}$ $Z_{\text{S}} = Z_{\text{Sopt}}, Z_{\text{L}} = 50 \Omega$	-	0.75	1.15	dB
Noise Figure (2)	NF2	$V_{CE} = 5 \text{ V, } I_{C} = 40 \text{ mA, } f = 1 \text{ GHz,}$ $Z_{S} = Z_{Sopt}, Z_{L} = Z_{Lopt}$	-	0.9	-	dB
Associated Gain (1)	Ga1	$V_{\text{CE}} = 5 \text{ V, Ic} = 10 \text{ mA, f} = 1 \text{ GHz,}$ $Z_{\text{S}} = Z_{\text{Sopt}}, \ Z_{\text{L}} = 50 \ \Omega$	10.0	12.0	-	dB
Associated Gain (2)	Ga2	$V_{CE} = 5 \text{ V, } I_{C} = 40 \text{ mA, } f = 1 \text{ GHz,}$ $Z_{S} = Z_{Sopt}, Z_{L} = Z_{Lopt}$	-	13.5	-	dB
Reverse Transfer Capacitance	Cre Note 2	VcB = 5 V, IE = 0 mA, f = 1 MHz	_	0.7	0.9	pF
Maximum Stable Power Gain	MSG Note 3	VcE = 5 V, Ic = 40 mA, f = 1 GHz	12.0	14.0	_	dB
Gain 1 dB Compression Output Power	Po (1 dB)	$V_{\text{CE}} = 5 \text{ V, Ic}_{\text{(set)}} = 40 \text{ mA, f} = 1 \text{ GHz,}$ $Z_{\text{S}} = Z_{\text{Sopt}}, \ Z_{\text{L}} = Z_{\text{Lopt}}$	-	21.5	-	dBm
Output 3rd Order Intercept Point	OIP <sub>3</sub>	$V_{\text{CE}} = 5 \text{ V, } I_{\text{C (set)}} = 40 \text{ mA, } f = 1 \text{ GHz,}$ $\Delta f = 1 \text{ MHz, } Z_{\text{S}} = Z_{\text{Sopt, }} Z_{\text{L}} = Z_{\text{Lopt}}$	_	35	_	dBm

**Notes 1.** Pulse measurement: PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2%

2. Collector to base capacitance when the emitter grounded.

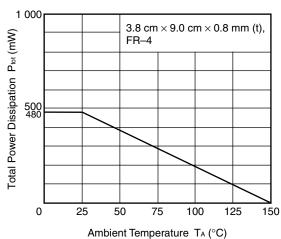
3. MSG = 
$$\frac{S_{21}}{S_{12}}$$

### **hfe CLASSIFICATION**

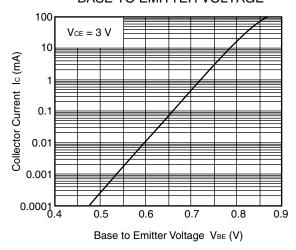
Rank	FB
Marking	R7B
h <sub>FE</sub> Value	140 to 260

#### TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

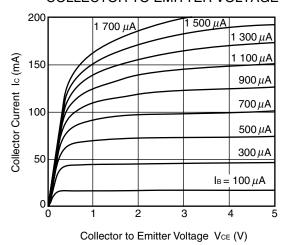
# TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



# COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

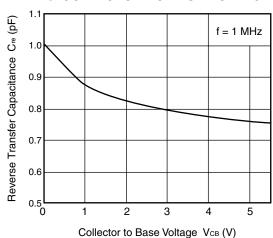


# COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

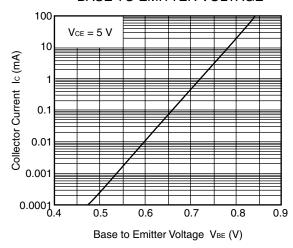


Remark The graphs indicate nominal characteristics.

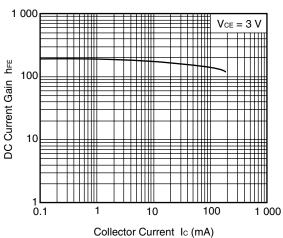
### REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



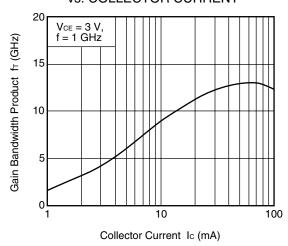
### COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



# DC CURRENT GAIN vs. COLLECTOR CURRENT

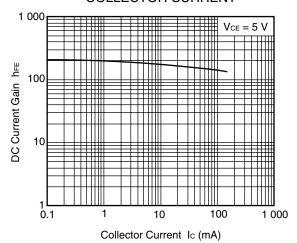


GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

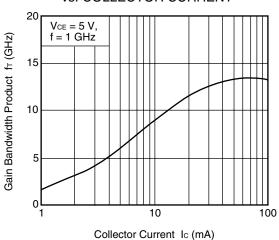


Remark The graphs indicate nominal characteristics.

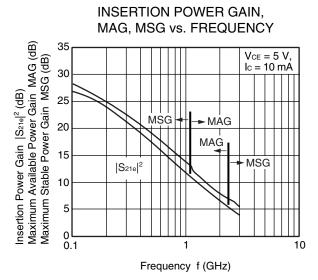
# DC CURRENT GAIN vs. COLLECTOR CURRENT

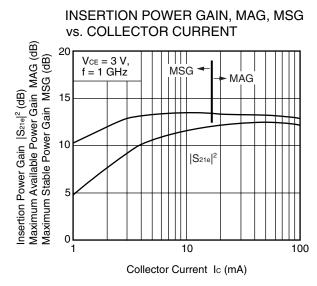


# GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

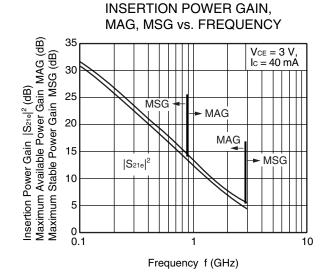


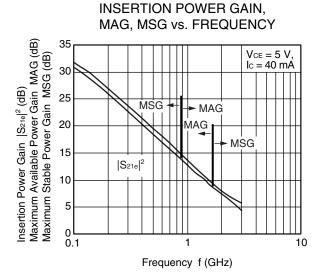
#### INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY Maximum Available Power Gain MAG (dB) Maximum Stable Power Gain MSG (dB) 35 VcE = 3 V, lc = 10 mA 30 Insertion Power Gain $|S_{21e}|^2$ (dB) 25 MAG 20 MAG 15 MSG |S<sub>21e</sub>|<sup>2</sup> 10 5 0∟ 0.1 1 10 Frequency f (GHz)

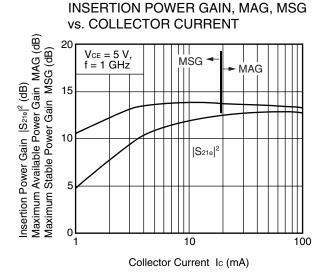




Remark The graphs indicate nominal characteristics.





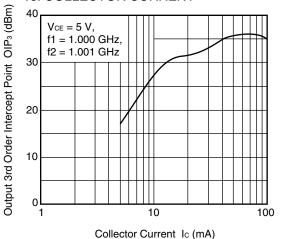


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### vs. COLLECTOR CURRENT 16 $V_{CE} = 5 V$ f = 1 GHz, 14 G $Z_S = Z_{Sopt}, Z_L = 50 \Omega$ G<sub>a</sub> (dB) 12 Noise Figure NF (dB) 10 Associated Gain 0 10 100

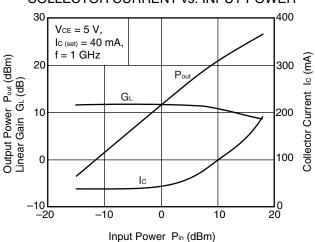
NOISE FIGURE, ASSOCIATED GAIN

#### **OUTPUT 3RD ORDER INTERCEPT POINT** vs. COLLECTOR CURRENT

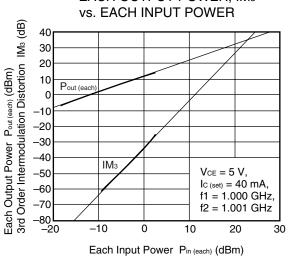


Collector Current Ic (mA)

**OUTPUT POWER, LINEAR GAIN,** COLLECTOR CURRENT vs. INPUT POWER



EACH OUTPUT POWER, IM3



Remark The graphs indicate nominal characteristics.

#### **S-PARAMETERS**

S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.

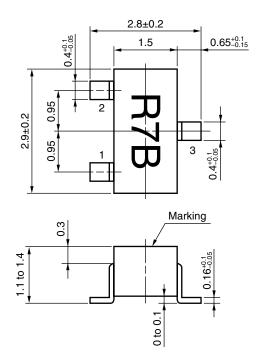
Click here to download S-parameters.

 $[\mathsf{RF} \ \mathsf{and} \ \mathsf{Microwave}] \to [\mathsf{Device} \ \mathsf{Parameters}]$ 

URL http://www.necel.com/microwave/en/

### PACKAGE DIMENSIONS

### 3-PIN MINIMOLD (33 PKG) (UNIT: mm)



### **PIN CONNECTIONS**

- 1. Emitter
- 2. Base
- 3. Collector

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